74AUP2G38

Low-power dual 2-input NAND gate; open drain

Rev. 9 — 26 March 2019

Product data sheet

1. General description

The 74AUP2G38 provides the dual 2-input NAND gate with open-drain output. The output of the device is an open drain and can be connected to other open-drain outputs to implement active-LOW wired-OR or active-HIGH wired-AND functions.

Schmitt trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial Power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing a damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; $I_{CC} = 0.9 \mu A$ (maximum)
- Latch-up performance exceeds 100 mA per JESD78B Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- IOFF circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

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3. Ordering information

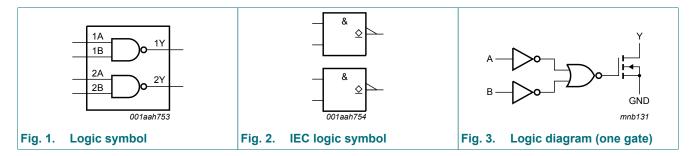
Type number	Package										
	Temperature range	Name	Description	Version							
74AUP2G38DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1							
74AUP2G38GT	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm	SOT833-1							
74AUP2G38GF	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1 × 0.5 mm	SOT1089							
74AUP2G38GM	-40 °C to +125 °C	XQFN8	plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.6 × 1.6 × 0.5 mm	SOT902-2							
74AUP2G38GN	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.2 × 1.0 × 0.35 mm	SOT1116							
74AUP2G38GS	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1.0 × 0.35 mm	SOT1203							

4. Marking

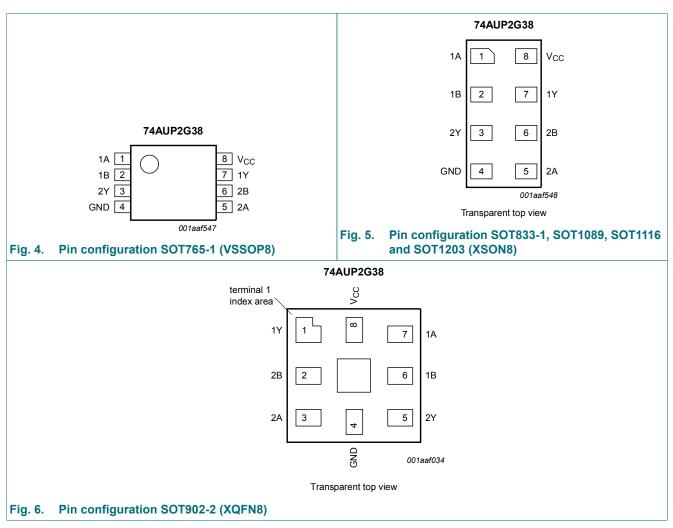
Table 2. Marking codes						
Type number	Marking code [1]					
74AUP2G38DC	a38					
74AUP2G38GT	a38					
74AUP2G38GF	aB					
74AUP2G38GM	a38					
74AUP2G38GN	aB					
74AUP2G38GS	aB					

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information



6.1. Pinning

6.2. Pin description

Table 3. Pin description

Symbol	Pin	Description	
	SOT765-1, SOT833-1, SOT1089, SOT1116 and SOT1203	SOT902-2	
1A, 2A	1, 5	7, 3	data input
1B, 2B	2, 6	6, 2	data input
GND	4	4	ground (0 V)
1Y, 2Y	7, 3	1, 5	data output
V _{CC}	8	8	supply voltage

7. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level; Z = high-impedance OFF state.

Input nA	Output	
nA	nB	nY
L	L	Z
L	Н	Z
Н	L	Z
Н	Н	L

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+4.6	V
I _{IK}	input clamping current	V ₁ < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+4.6	V
I _{ОК}	output clamping current	V _O < 0 V		-50	-	mA
Vo	output voltage	Active mode and Power-down mode	[1]	-0.5	+4.6	V
I _O	output current	$V_{O} = 0 V \text{ to } V_{CC}$		-	+20	mA
I _{CC}	supply current			-	+50	mA
I _{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T_{amb} = -40 °C to +125 °C	[2]	-	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For VSSOP8 packages: above 110 °C the value of Ptot derates linearly at 8.0 mW/K.

For XSON8 and XQFN8 packages: above 118 °C the value of Ptot derates linearly with 7.8 mW/K.

9. Recommended operating conditions

Table 6. Operating conditions

Symbol	Parameter Conditions		Min	Мах	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode and Power-down mode	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 0.8 V to 3.6 V	0	200	ns/V

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
T _{amb} = 2	25 °C					
V _{IH}	HIGH-level input	V _{CC} = 0.8 V	0.70V _{CC}	-	-	V
	voltage	V _{CC} = 0.9 V to 1.95 V	0.65V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input	V _{CC} = 0.8 V	-	-	0.30V _{CC}	V
	voltage	V _{CC} = 0.9 V to 1.95 V	-	-	0.35V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OL}	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$				
	voltage	I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V
l _l	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.1	μA
I _{OFF}	power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.2	μA
∆I _{OFF}	additional power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V to 0.2 V	-	-	±0.2	μA
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V	-	-	0.5	μA
ΔI _{CC}	additional supply current	$V_{\rm I} = V_{\rm CC} - 0.6 \text{ V}; \text{ I}_{\rm O} = 0 \text{ A}; \text{ V}_{\rm CC} = 3.3 \text{ V}$	-	-	40	μA
CI	input capacitance	V_{CC} = 0 V to 3.6 V; V _I = GND or V _{CC}	-	0.7	-	pF
C _O	output capacitance	$V_0 = GND; V_{CC} = 0 V$	-	0.9	-	pF
	40 °C to +85 °C					1.
V _{IH}	HIGH-level input	V _{CC} = 0.8 V	0.70V _{CC}	-	-	V
	voltage	V _{CC} = 0.9 V to 1.95 V	0.65V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	2.0	-	-	V
V _{IL}	LOW-level input	V _{CC} = 0.8 V	-	-	0.30V _{CC}	V
	voltage	$V_{CC} = 0.9 \text{ V to } 1.95 \text{ V}$	-	_	0.35V _{CC}	V
		$V_{\rm CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	-	0.7	V
		$V_{\rm CC} = 3.0 \text{V} \text{ to } 3.6 \text{V}$				V

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OL}	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$				
	voltage	I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V
l _l	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.5	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.5	μA
I _{OFF}	power-off leakage current	V_1 or V_0 = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.5	μA
ΔI _{OFF}	additional power-off leakage current	V_1 or V_0 = 0 V to 3.6 V; V_{CC} = 0 V to 0.2 V	-	-	±0.6	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.9	μA
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$	-	-	50	μA
T _{amb} = -4	40 °C to +125 °C				1	-
VIH	HIGH-level input	V _{CC} = 0.8 V	0.75V _{CC}	-	-	V
	voltage	V _{CC} = 0.9 V to 1.95 V	0.70V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input	V _{CC} = 0.8 V	-	-	0.25V _{CC}	V
	voltage	V _{CC} = 0.9 V to 1.95 V	-	-	0.30V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OL}	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$				
	voltage	I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V

6 / 18

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
l _l	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.75	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.75	μA
I _{OFF}	power-off leakage current	$V_{1} \text{ or } V_{0} = 0 \text{ V to } 3.6 \text{ V; } V_{CC} = 0 \text{ V}$	-	-	±0.75	μA
ΔI _{OFF}	additional power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V to 0.2 V	-	-	±0.75	μA
I _{CC}	supply current	$V_1 = GND \text{ or } V_{CC}; I_0 = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	1.4	μA
ΔI _{CC}	additional supply current	V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	-	-	75	μA

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 8.

Symbol	Parameter	Conditions		25 °C		-40	°C to +1	25 °C	Unit
			Min	Тур <mark>[1]</mark>	Мах	Min	Max (85 °C)	Max (125 °C)	-
C _L = 5 p	F						·		
t _{pd}	propagation	nA, nB to nY; see <u>Fig. 7</u> [2]							
	delay	V _{CC} = 0.8 V	-	13.5	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	1.9	4.6	10.4	1.8	11.4	12.6	ns
		V _{CC} = 1.4 V to 1.6 V	1.5	3.3	6.5	1.4	7.4	8.2	ns
		V _{CC} = 1.65 V to 1.95 V	1.2	2.9	5.1	1.1	5.9	6.5	ns
		V_{CC} = 2.3 V to 2.7 V	1.0	2.2	3.8	0.9	4.5	4.9	ns
		V _{CC} = 3.0 V to 3.6 V	0.9	2.3	4.0	0.8	4.5	4.9	ns
C _L = 10	pF	· · ·							
t _{pd}	propagation	nA, nB to nY; see Fig. 7 [2]							
	delay	V _{CC} = 0.8 V	-	16.3	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.3	5.6	12.3	2.1	13.7	15.1	ns
		V _{CC} = 1.4 V to 1.6 V	1.8	4.1	7.6	1.7	8.8	9.7	ns
		V _{CC} = 1.65 V to 1.95 V	1.6	3.8	6.1	1.4	7.1	7.8	ns
		V _{CC} = 2.3 V to 2.7 V	1.4	2.9	4.6	1.2	5.4	5.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.3	3.2	5.7	1.1	6.4	7.0	ns
C _L = 15	pF					L		1	1
t _{pd}	propagation	nA, nB to nY; see Fig. 7 [2]							
	delay	V _{CC} = 0.8 V	-	19.0	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.6	6.6	14.2	2.4	15.8	17.4	ns
		V _{CC} = 1.4 V to 1.6 V	2.1	4.8	8.7	1.9	10.1	11.1	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	4.6	7.6	1.7	8.5	9.3	ns
		$V_{\rm CC}$ = 2.3 V to 2.7 V	1.6	3.6	5.6	1.5	6.3	6.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.6	4.1	7.5	1.4	8.3	9.1	ns

Symbol	Parameter	Conditions			25 °C		-40	°C to +12	25 °C	Unit
			-	Min	Typ [1]	Мах	Min	Max (85 °C)	Max (125 °C)	
C _L = 30	pF						I			
t _{pd}	propagation	nA, nB to nY; see Fig. 7	[2]							
	delay	V _{CC} = 0.8 V		-	27.0	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V		3.6	9.5	19.5	3.2	21.8	24.0	ns
		V _{CC} = 1.4 V to 1.6 V		2.9	7.0	11.5	2.6	13.6	15.0	ns
		V _{CC} = 1.65 V to 1.95 V		2.6	7.0	12.1	2.3	13.3	14.6	ns
		V _{CC} = 2.3 V to 2.7 V		2.4	5.4	8.9	2.1	9.9	10.9	ns
		V _{CC} = 3.0 V to 3.6 V		2.3	6.5	12.7	2.1	13.9	15.3	ns
C _L = 5 p	F, 10 pF, 15 pF	and 30 pF								
C _{PD}	power	$f = 1 \text{ MHz}; V_I = \text{GND to } V_{CC}$	[3]							
	dissipation capacitance	V _{CC} = 0.8 V		-	0.6	-	-	-	-	pF
	capacitance	V _{CC} = 1.1 V to 1.3 V		-	0.7	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V		-	0.8	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V		-	0.9	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V		-	1.1	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V		-	1.4	-	-	-	-	pF

All typical values are measured at nominal V_{CC} . [1]

[2]

 t_{pd} is the same as t_{PZL} and t_{PLZ} . C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N$ where: [3]

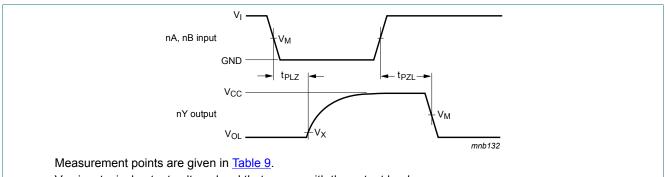
f_i = input frequency in MHz;

V_{CC} = supply voltage in V;

N = number of inputs switching.

74AUP2G38

11.1. Waveforms and test circuit



V_{OL} is a typical output voltage level that occurs with the output load.

Fig. 7. The data input (nA, nB) to output (nY) propagation delays

Table 9. Measurement points

Supply voltage	Input	Output			
V _{cc}	V _M	V _M	V _X		
0.8 V to 1.6 V	0.5V _{CC}	0.5V _{CC}	V _{OL} + 0.1 V		
1.65 V to 2.7 V	0.5V _{CC}	0.5V _{CC}	V _{OL} + 0.15 V		
3.0 V to 3.6 V	0.5V _{CC}	0.5V _{CC}	V _{OL} + 0.3 V		

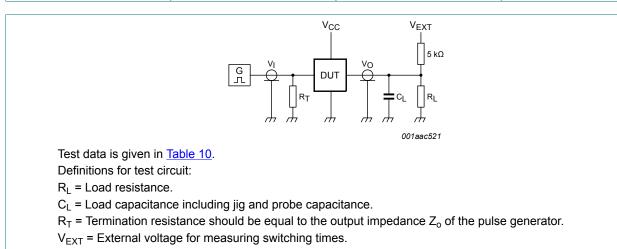


Fig. 8. Test circuit for measuring switching times

Table 10. Test data

Supply voltage	Load		V _{EXT}		
V _{cc}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2V _{CC}

[1] For measuring enable and disable times $R_L = 5 k\Omega$.

For measuring propagation delays, set-up times, hold times and pulse width, R_L = 1 M Ω .

12. Package outline

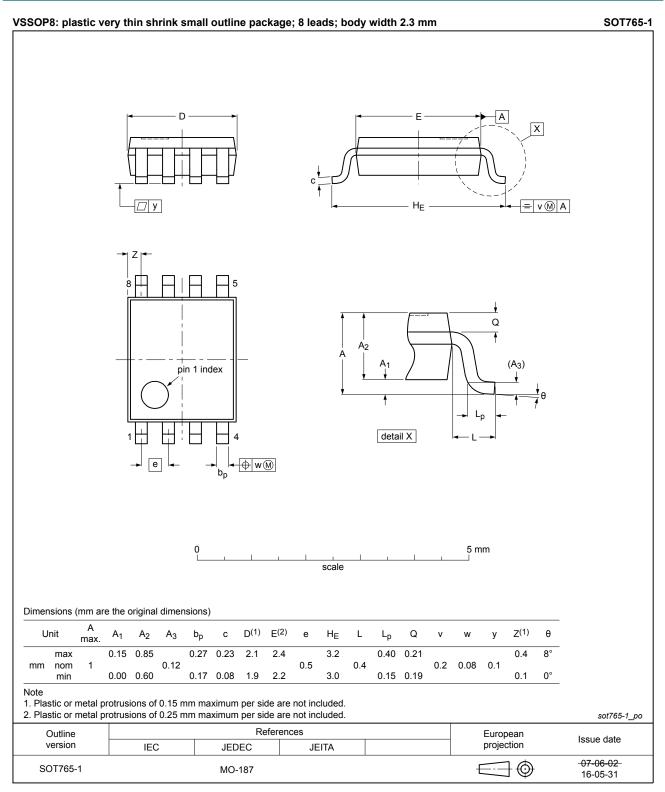


Fig. 9. Package outline SOT765-1 (VSSOP8)

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Low-power dual 2-input NAND gate; open drain

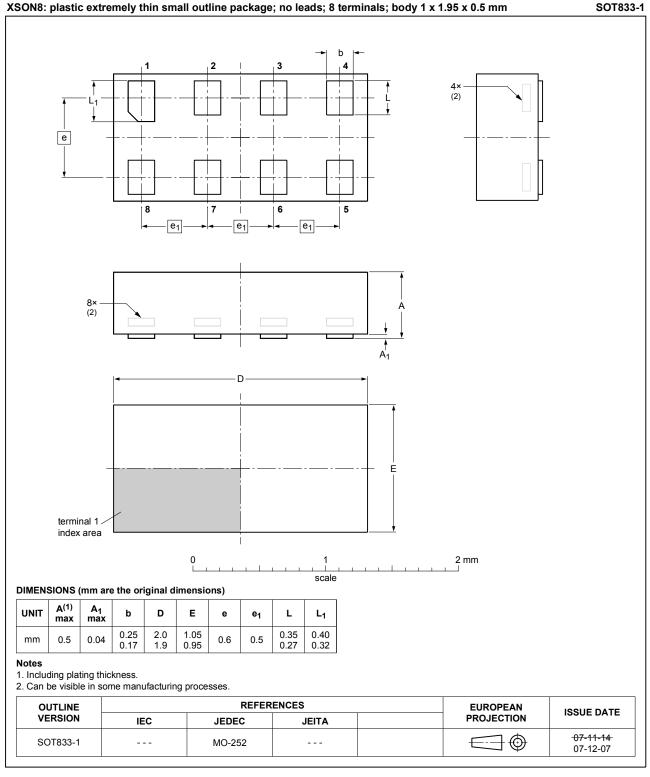
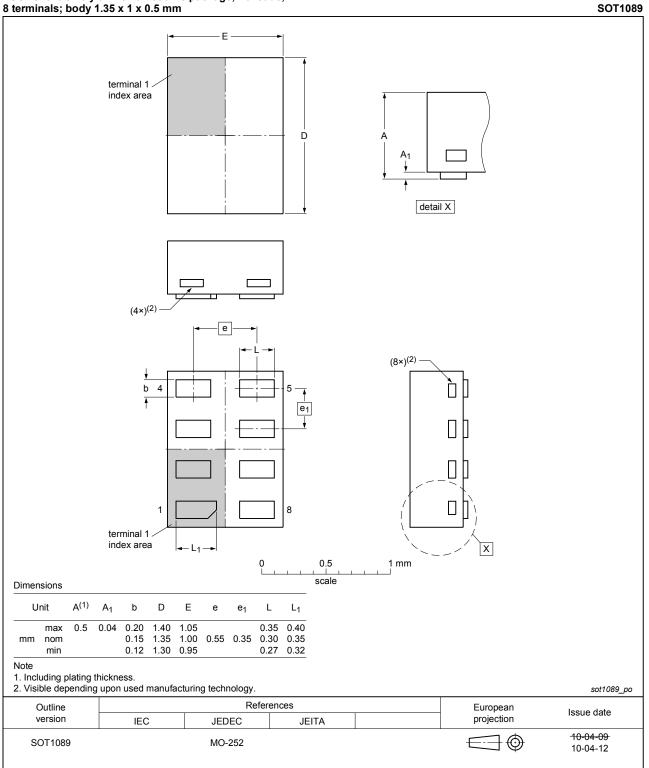


Fig. 10. Package outline SOT833-1 (XSON8)



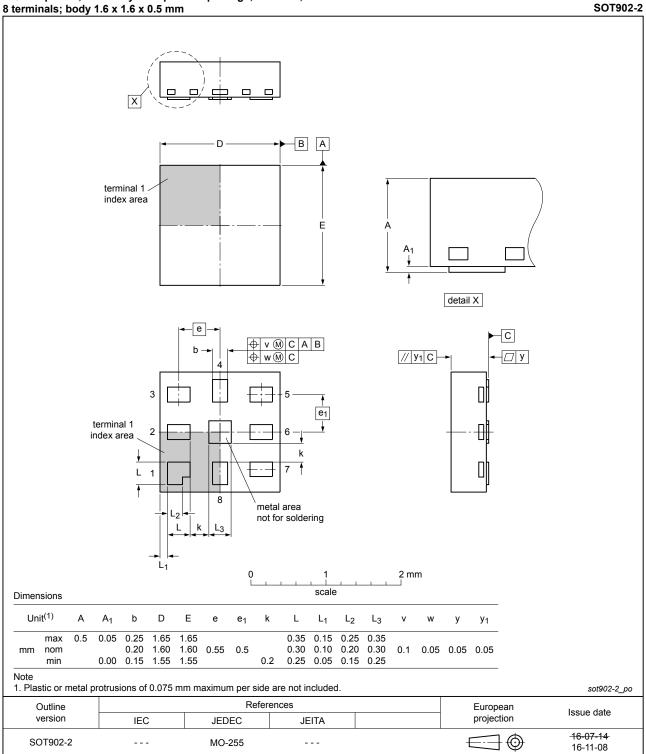
XSON8: extremely thin small outline package; no leads;

Fig. 11. Package outline SOT1089 (XSON8)

12/18

74AUP2G38

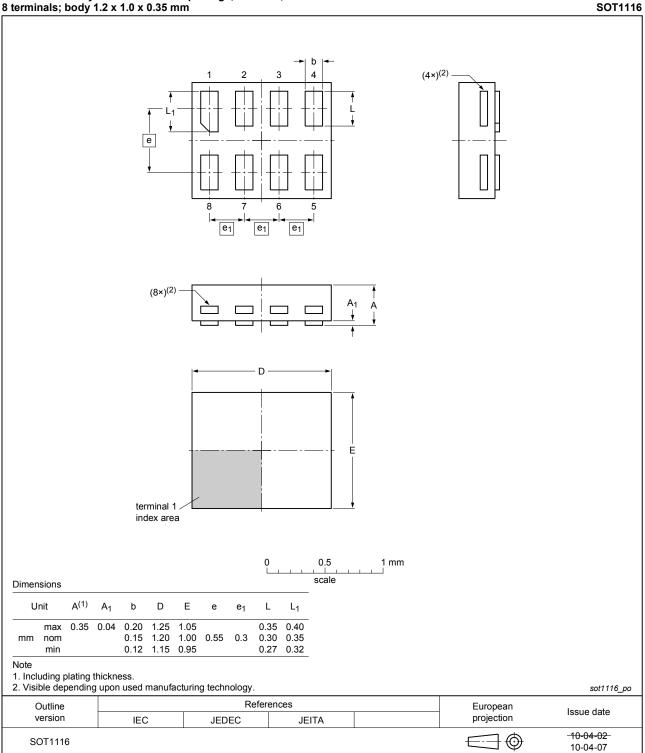
Low-power dual 2-input NAND gate; open drain



XQFN8: plastic, extremely thin quad flat package; no leads; 8 terminals: body 1.6 x 1.6 x 0.5 mm

Fig. 12. Package outline SOT902-2 (XQFN8)

XSON8: extremely thin small outline package; no leads; 8 terminals; body 1.2 x 1.0 x 0.35 mm





XSON8: extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1.0 x 0.35 mm SOT1203 b (4×)⁽²⁾ 4 2 3 е 8 6 e₁ e₁ e₁ $(8 \times)^{(2)}$ А С С ٦ D E terminal 1 index area 0.5 1 mm 0 1 1 . scale Dimensions Unit A⁽¹⁾ A₁ b D Е L е e₁ L_1 0.35 0.04 0.20 1.40 1.05 0.35 0.40 max 0.15 1.00 $0.55 \quad 0.35 \quad 0.30 \quad 0.35$ mm nom 1.35 min 0.12 1.30 0.95 0.27 0.32 Note 1. Including plating thickness. 2. Visible depending upon used manufacturing technology. sot1203_po References Outline European Issue date version projection IEC JEDEC JEITA 10-04-02 SOT1203 \blacksquare 10-04-06

Fig. 14. Package outline SOT1203 (XSON8)

13. Abbreviations

Table 11. Abbreviations			
Acronym	Description		
CDM	Charged Device Model		
DUT	Device Under Test		
ESD	ElectroStatic Discharge		
НВМ	Human Body Model		
MM	Machine Model		

14. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74AUP2G38 v.9	20190326	Product data sheet	-	74AUP2G38 v.8		
Modifications:	of Nexperia • Legal texts • Type numb	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Type numbers 74AUP2G38GD (SOT996-2) removed. Package outline drawing <u>SOT765-1</u> (VSSOP8) updated. 				
	•	Package outline drawing <u>SOT902-2</u> (XQFN8) updated.				
74AUP2G38 v.8	20130211	Product data sheet	-	74AUP2G38 v.7		
Modifications:	For type nu	For type number 74AUP2G38GD XSON8U has changed to XSON8.				
74AUP2G38 v.7	20120605	Product data sheet	-	74AUP2G38 v.6		
74AUP2G38 v.6	20111209	Product data sheet	-	74AUP2G38 v.5		
74AUP2G38 v.5	20100923	Product data sheet	-	74AUP2G38 v.4		
74AUP2G38 v.4	20091008	Product data sheet	-	74AUP2G38 v.3		
74AUP2G38 v.3	20090616	Product data sheet	-	74AUP2G38 v.2		
74AUP2G38 v.2	20080312	Product data sheet	-	74AUP2G38 v.1		
74AUP2G38 v.1	20061016	Product data sheet	-	-		

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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Product data sheet

Contents

1. General description	1
2. Features and benefits	1
3. Ordering information	2
4. Marking	2
5. Functional diagram	2
6. Pinning information	3
6.1. Pinning	3
6.2. Pin description	3
7. Functional description	4
8. Limiting values	4
9. Recommended operating conditions	4
10. Static characteristics	5
11. Dynamic characteristics	7
11.1. Waveforms and test circuit	9
12. Package outline	10
13. Abbreviations	16
14. Revision history	16
15. Legal information	17

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